





### 1st Production Batch

- Ordered 4 Lots with 25 wafer each end of 2014

Institut

- → 80 wafers to be delivered (assuming 80% yield)
- Status 2015
  - 3 lots delivered in mid 2015:
    - lot 341774
    - · lot 341775
    - · lot 341776
  - Only sensors that passed the tests are delivered to Giessen
  - So far: low yield







#### 1st Production Batch

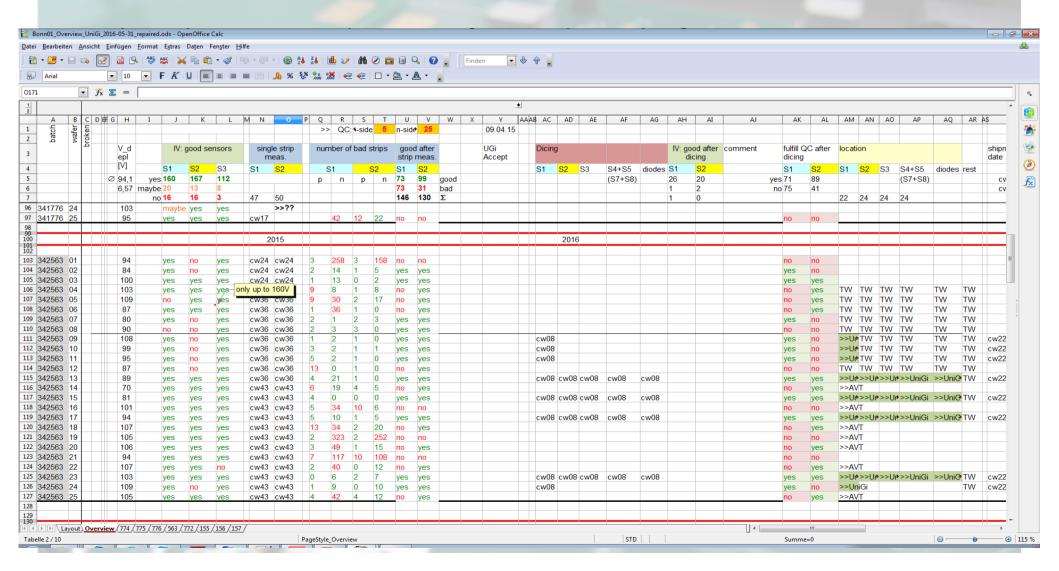
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  - → 80 wafers to be delivered (assuming 80% yield)
- Status 2015
  - 3 lots delivered in mid 2015:
    - · lot 341774
    - · lot 341775
    - · lot 341776
- Update 2016
- 3 lots delivered in May 2016:
  - · lot 342563
  - · lot 341772
  - · lot 352157
- Still low yield but there is hope …







#### 1st Production Batch









- Yield overview first 3 lots

Lot	b65 (S1)	m65 (S2)
341774	5 (20%)	10 (40%)
341775	1 (4%)	2 (8%)
341776	7 (28%)	9 (36%)
total	13 (17%)	21 (28%)

- Reasons for exclusion/failed test

Reason	b65 (S1)	m65 (S2)
IV excluded	24 (32%)	13 (17%)
pin-hole excluded	32 (43%)	20 (27%)
broken/missing	1 (1%)	4 (5%)
"omitted"	5 (7%)	17 (23%)







- 3 new lots delivered
- produced 2015 and 2016
- time needed to investigate issues
- Production year
  - lot 342563 2015
  - lot 341772 2016
  - lot 352157 2016 (different wafer material)





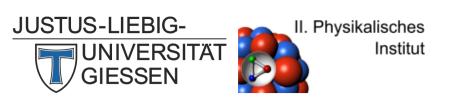


- Yield overview new 3 lots

Lot	b65 (S1)	m65 (S2)
342563	8 (32%)	4 (16%)
341772	3 (12%)	2 (8%)
352157	17 (68%)	16 (64%)
total	28 (37%)	22 (29%)

- Reasons for exclusion/failed test

Reason	b65 (S1)	m65 (S2)
IV excluded	3 (4%)	12 (16%)
pin-hole excluded	31 (41%)	8 (11%)
broken/missing	5 (7%)	6 (8%)
"omitted"	8 (11%)	27 (36%)





- Characteristics compared qualitatively to first delivery
  - Lot 342563
    - leakage current very low to intermediate
    - breakdown voltage OK (mostly >300V)
    - high pin-hole count (mostly n-side)
  - Lot 341772
    - leakage current low to intermediate
    - small breakdown voltage (220-280V)
    - vey high pin-hole count (mostly n-side)
  - Lot 352157
    - leakage current very low to low ( <1µA @100V for S1)</li>
    - high breakdown voltage (sometimes not reached at 500V)
    - low pin-hole count (several sensors with 0 on p- and n-side)





# Outlook (the hope)

- Problems identified: surface of wafer backside (n-side)
- Last lot (352157) looks very promising
- used different wafer material (according to CiS)
- 2 more lots already produced (352155, 352156)
- not fully measured and diced
  - Lot 352155
    - leakage current very low to low
    - high breakdown voltage
    - low pin-hole count (several defect free sensors)
  - Lot 352156
    - leakage current low to intermediate
    - high breakdown voltage
    - only a subset of pin-hole data available until now





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#### **Total Inventory**

	b65 (S1)	m65 (S2)
Sum	41	46







